PC1231xNSZ0F **Series**

DIP 4pin Reinforced Insulation Type, **High CMR, Low Input Current Photocoupler**



Description

PC1231xNSZ0F Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4-pin DIP, available in wide-lead spacing option and SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV. CTR is 50% to 400% at input current of 0.5mA.

Features

- 1. 4pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. Low input current type (I_F=0.5mA)
- 4. High resistance to noise due to high common rejection voltage (CMR : MIN. 10kV/us)
- 5. Reinforced insulation type (Isolation distance : MIN. 0.4mm)
- 6. Long creepage distance type (wide lead-form type only: MIN. 8mm)
- 7. High isolation voltage between input and output $(V_{iso(rms)}: 5.0kV)$
- 8. Lead-free and RoHS directive compliant

Agency approvals/Compliance

- 1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC1231)
- 2. Approved by BSI, BS-EN60065, file No. 7087, BS-EN60950, file No. 7409, (as model No. PC1231)
- 3. Approved by SEMCO, EN60065, EN60950, file No. 9933036 (as model No. PC1231)
- 4. Approved by DEMCO, EN60065, EN60950, file No. 99-03814 (as model No. PC1231)
- 5. Approved by NEMKO, EN60065, EN60950, file No. P99102251 (as model No. PC1231)
- 6. Approved by FIMKO, EN60065, EN60950, file No. 13986 (as model No. PC1231)
- 7. Recognized by CSA file No. CA095323 (as model No. PC1231)
- 8. Approved by VDE, DIN EN60747-5-2^(*) (as an option), file No. 40008087(as model No. PC1231)
- 9. Package resin : UL flammability grade (94V-0)

(*) DIN EN60747-5-2 : successor standard of DIN VDE0884

Applications

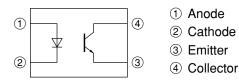
- 1. Primary to secondary isolation in switch mode power supply
- 2. Noise suppression in switching circuit
- 3. Signal transmission between circuits of different potentials and impedances
- 4. Over voltage detection

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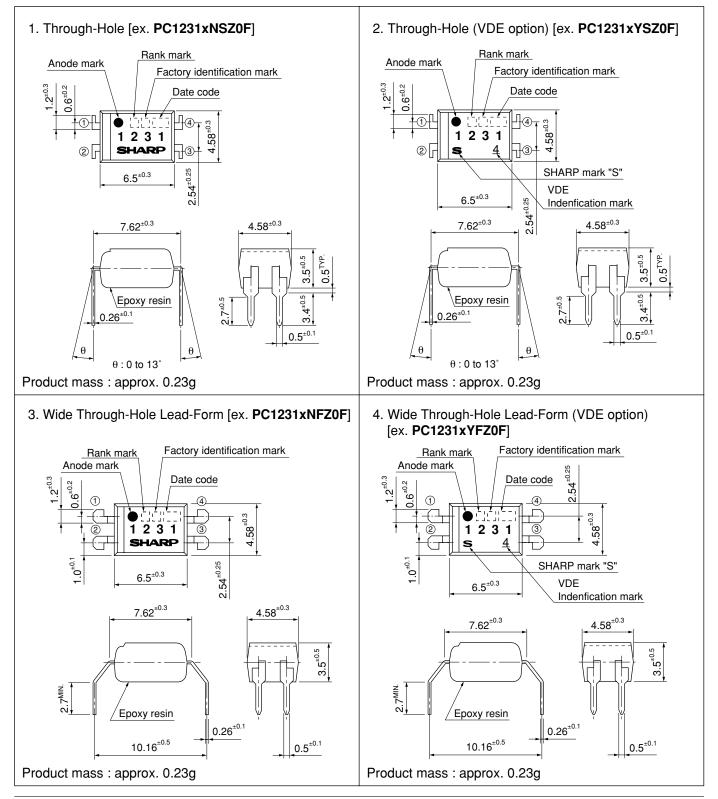


Internal Connection Diagram



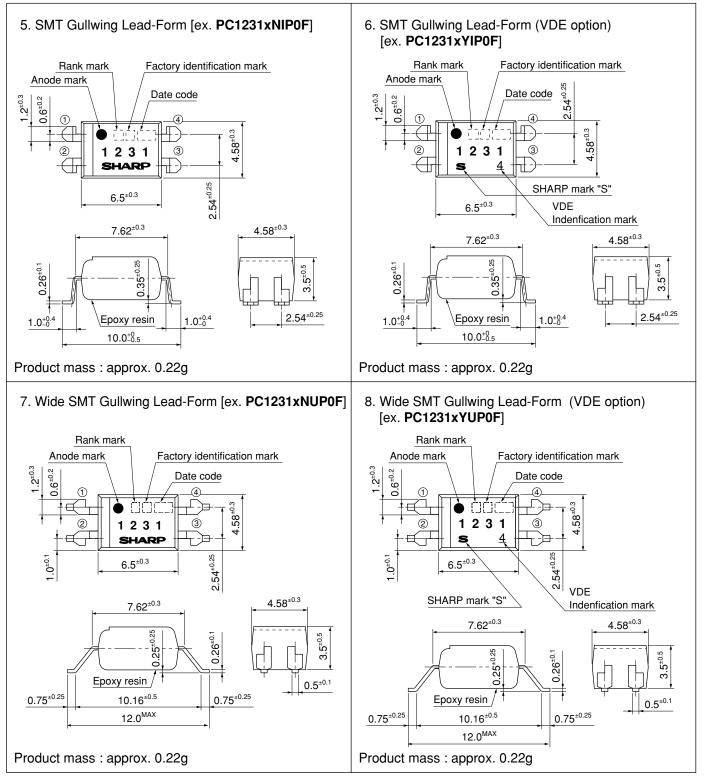
Outline Dimensions

(Unit : mm)





(Unit : mm)



Plating material : SnCu (Cu : TYP. 2%)



Date code (2 digit)

	1st o	digit		2nd digit				
	Year of p	roduction		Month of	production			
A.D.	Mark	A.D	Mark	Month	Mark			
1990	A	2002	Р	January	1			
1991	В	2003	R	February	2			
1992	С	2004	S	March	3			
1993	D	2005	Т	April	4			
1994	Е	2006	U	May	5			
1995	F	2007	V	June	6			
1996	Н	2008	W	July	7			
1997	J	2009	Х	August	8			
1998	K	2010	А	September	9			
1999	L	2011	В	October	0			
2000	М	2012	С	November	N			
2001	N	:	:	December	D			
	I	1	1	1	I			

repeats in a 20 year cycle

Factory identification mark

Factory identification Mark	Country of origin	
no mark	Inner	
	Japan	
	Indonesia	
	China	

* This factory marking is for identification purpose only. Please contact the local SHARP sales representative to see the actual status of the production.

Rank mark

Refer to the Model Line-up table

■ Absolute Maximum Ratings

	Absolute Maximum Ratings (T _a =25°C)						
	Parameter	Symbol	Rating	Unit			
	Forward current	$I_{\rm F}$	10	mA			
Input	*1 Peak forward current	I _{FM}	200	mA			
Inț	Reverse voltage	V _R	6	V			
	Power dissipation	Р	15	mW			
	Collector-emitter voltage	V _{CEO}	70	V			
Output	Emitter-collector voltage	V _{ECO}	6	V			
Out	Collector current	I _C	50	mA			
	Collector power dissipation	P _C	150	mW			
Total power dissipation		P _{tot}	170	mW			
*2 Isolation voltage		V _{iso (rms)}	5.0	kV			
Operating temperature		T _{opr}	-30 to +100	°C			
Storage temperature		T _{stg}	-55 to +125	°C			
*3 🤆	Soldering temperature	T _{sol}	260	°C			

*1 Pulse width≤100μs, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute, f=60Hz *3 For 10s

■ Electro-optical Characteristics

Electric	ctro-optica	I Chara	acteristi	CS				$(T_a=25^{\circ}C)$
	Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	Forward volta	ıge	$V_{\rm F}$	I _F =10mA	-	1.2	1.4	V
Input	Reverse curre	nt	I _R	V _R =4V	-	-	10	μA
	Terminal capa	acitance	Ct	V=0, f=1kHz	-	30	250	pF
	Collector dark	current	I _{CEO}	$V_{CE}=50V, I_{F}=0$	_	_	100	nA
Output	Collector-emitter breakdown voltage		BV_{CEO}	$I_{C}=0.1 \text{mA}, I_{F}=0$	70	-	-	V
	Emitter-collector breakdown voltage		BV _{ECO}	$I_E=10\mu A, I_F=0$	6	-	-	V
	Collector current		I _C	$I_F=0.5$ mA, $V_{CE}=5$ V	0.25	_	2.0	mA
	Collector-emitter saturation voltage		V _{CE (sat)}	$I_F=10mA$, $I_C=1mA$	-	_	0.2	V
	Isolation resistance		R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	-	Ω
Transfer	Floating capa	citance	$C_{\rm f}$	V=0, f=1MHz	-	0.6	1.0	pF
charac- teristics	Description	Rise time	t _r	V 2V I 2. A D 1000	-	4	18	μs
	Response time	Fall time	t _f	$V_{CE}=2V$, $I_C=2mA$, $R_L=100\Omega$	_	3	18	μs
	Common mode rejection voltage		CMR	V_{CM} =1.5kV(peak), I _F =0 R _L =470 Ω , V _{CC} =9V, V _{np} =100mV	10	-	-	kV/µs



■ Model Line-up

Lead Form	Trough-Hole Wide Trough-Hole			T. F.,. A 1		
Package		Sle	eve	Rank mark	I_{C} [mA] (I _F =0.5mA, V _{CE} =5V, T _a =25°C)	
Fackage		100pcs	s/sleeve		(1F-0.5mA, VCE-5V, 1a-25C)	
DIN EN60747-5-2		Approved		Approved		
Model No.	PC12310NSZ0F	PC12310YSZ0F	PC12310NFZ0F	PC12310YFZ0F	with or without	0.25 to 2.0
Model No.	PC12311NSZ0F	PC12311YSZ0F	PC12311NFZ0F	PC12311YFZ0F	А	0.5 to 1.25

L	ead Form	SMT G	SMT Gullwing Wide SMT Gullwing				T [A]	
	Taping					Rank mark	I_{C} [mA] ($I_{F}=0.5$ mA, $V_{CF}=5V$, $T_{a}=25^{\circ}$ C)	
	Package		2 000pcs/reel				$(1_{\rm E}-0.511_{\rm H}, V_{\rm CE}-5V, 1_{\rm a}-25C)$	
DIN	EN60747-5-2		Approved		Approved			
	adal Na	PC12310NIP0F	PC12310YIP0F	PC12310NUP0F	PC12310YUP0F	with or without	0.25 to 2.0	
IV	Model No.	PC12311NIP0F	PC12311YIP0F	PC12311NUP0F	PC12311YUP0F	А	0.5 to 1.25	

Please contact a local SHARP sales representative to inquire about production status.



Fig.1 Test Circuit for Common Mode Rejection Voltage

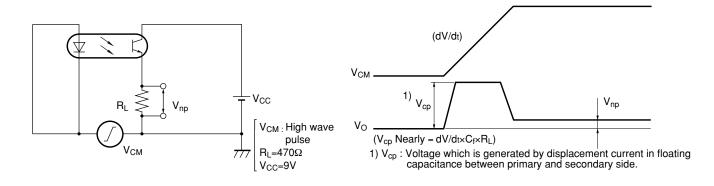
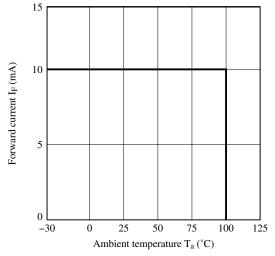


Fig.2 Forward Current vs. Ambient Temperature





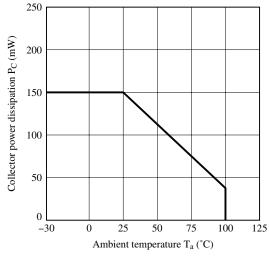


Fig.3 Diode Power Dissipation vs. Ambient Temperature

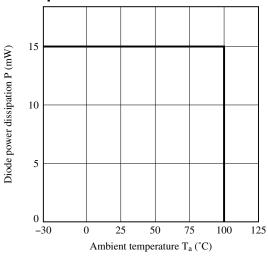


Fig.5 Total Power Dissipation vs. Ambient Temperature

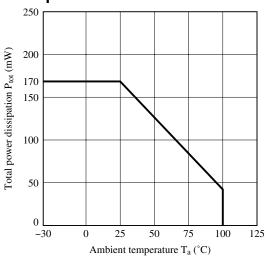
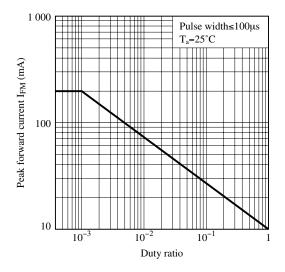
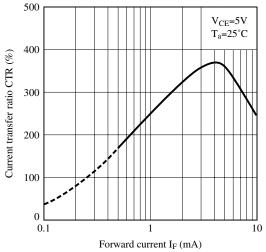


Fig.6 Peak Forward Current vs. Duty Ratio

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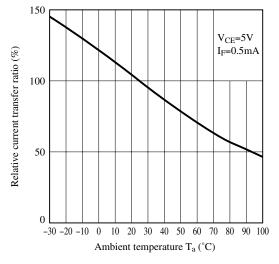


Fig.7 Forward Current vs. Forward Voltage

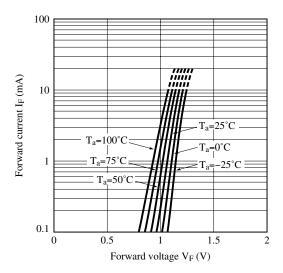


Fig.9 Collector Current vs. Collector-emitter Voltage

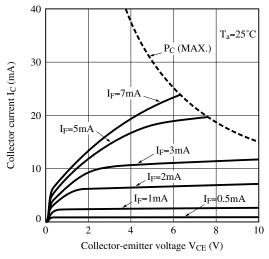


Fig.11 Collector - emitter Saturation Voltage vs. Ambient Temperature

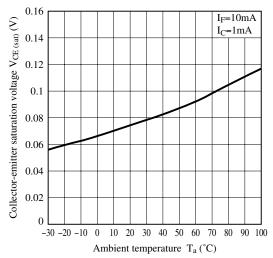


Fig.12 Collector Dark Current vs. Ambient Temperature

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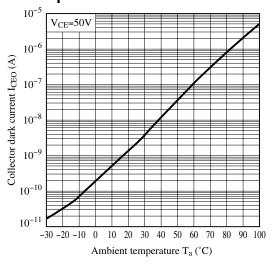
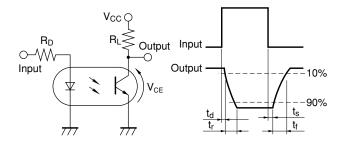
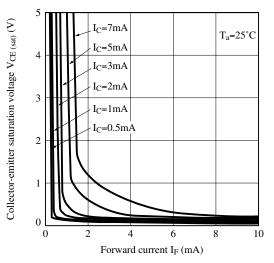


Fig.14 Test Circuit for Response Time



Please refer to the conditions in Fig.13.

Fig.16 Collector-emitter Saturation Voltage vs. Forward Current





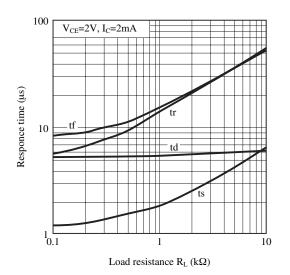
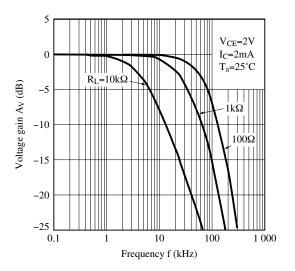


Fig.15 Frequency Response



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



Design Considerations

Design guide

While operating at I_F<0.5mA, CTR variation may increase. Please make design considering this fact.

In case that some sudden big noise caused by voltage variation is provided between primary and secondary terminals of photocoupler some current caused by it is floating capacitance may be generated and result in false operation since current may go through IRED or current may change.

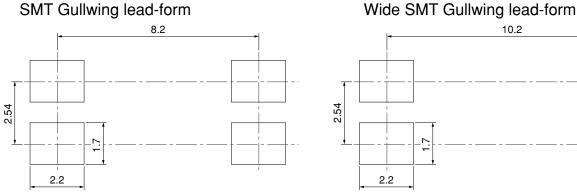
If the photocoupler may be used under the circumstances where noise will be generated we recommend to use the bypass capacitors at the both ends of IRED.

This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time. In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Recommended Foot Print (reference)



10.2 (Unit : mm)

☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

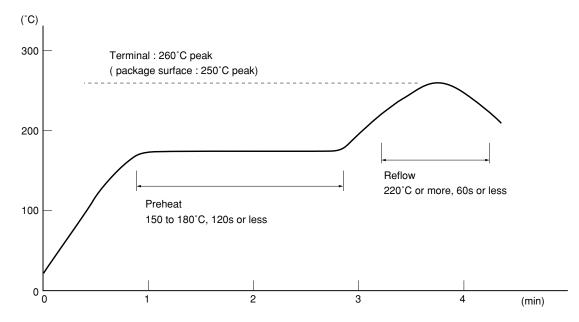


Manufacturing Guidelines

Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below. Soldering should not exceed the curve of temperature profile and time. Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s. Preheating is within the bounds of 100 to 150°C and 30 to 80s. Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C. Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



• Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials. And they are not used in the production process for this product. Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).
•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



Package specification

• Sleeve package

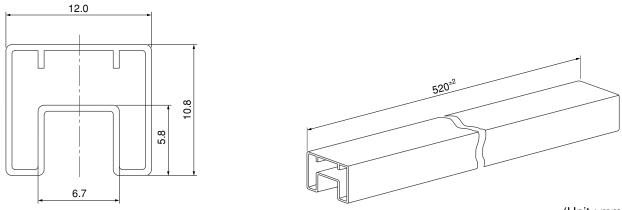
1. Through-Hole

Package materials Sleeve : HIPS (with anti-static material) Stopper : Styrene-Elastomer

Package method

MAX. 100pcs of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers. The product shall be arranged in the sleeve with its anode mark on the tabless stopper side. MAX. 20 sleeves in one case.

Sleeve outline dimensions



(Unit : mm)

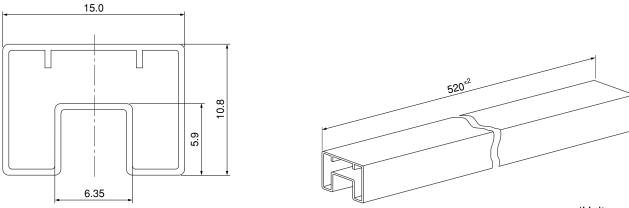
2. Wide Through-Hole

Package materials Sleeve : HIPS (with anti-static material) Stopper : Styrene-Elastomer

Package method

MAX. 100pcs of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers. The product shall be arranged in the sleeve with its anode mark on the tabless stopper side. MAX. 20 sleeves in one case.

Sleeve outline dimensions

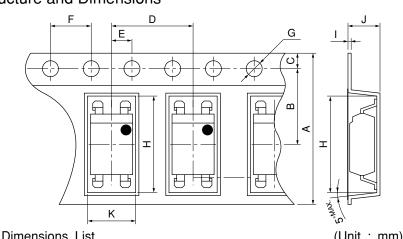




• Tape and Reel package

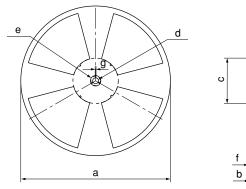
1. SMT Gullwing

Package materials Carrier tape : PS Cover tape : PET (three layer system) Reel : PS Carrier tape structure and Dimensions



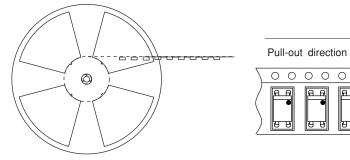
В	С	D	Е	F	G	
$7.5^{\pm 0.1}$	$1.75^{\pm 0.1}$	$8.0^{\pm 0.1}$	$2.0^{\pm 0.1}$	$4.0^{\pm 0.1}$	φ1.5 ^{+0.1}	
Ι	J	K				
$0.4^{\pm 0.05}$	$4.2^{\pm 0.1}$	$5.1^{\pm 0.1}$				
	В 7.5 ^{±0.1} І	B C 7.5 ^{±0.1} 1.75 ^{±0.1} I J	$\begin{array}{c ccc} B & C & D \\ \hline 7.5^{\pm 0.1} & 1.75^{\pm 0.1} & 8.0^{\pm 0.1} \\ I & J & K \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	

Reel structure and Dimensions



Dimensio	ns List	(Unit : mm)		
а	b	с	d	
330	$17.5^{\pm 1.5}$	$100^{\pm 1.0}$	13 ^{±0.5}	
e	f	g		
23 ^{±1.0}	$2.0^{\pm 0.5}$	$2.0^{\pm 0.5}$		

Direction of product insertion



[Packing : 2 000pcs/reel]

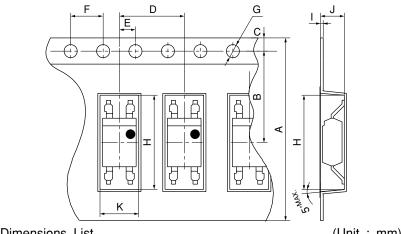
A



2. Wide SMT Gullwing

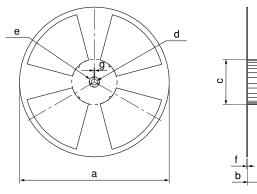
Package materials Carrier tape : PS Cover tape : PET (three layer system) Reel : PS

Carrier tape structure and Dimensions



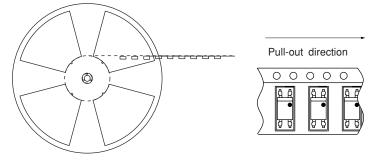
Dimension	Dimensions List (Unit : mm)						
А	В	С	D	Е	F	G	
24.0 ^{±0.3}	$11.5^{\pm 0.1}$	$1.75^{\pm 0.1}$	$8.0^{\pm 0.1}$	$2.0^{\pm 0.1}$	$4.0^{\pm 0.1}$	φ1.5 ^{+0.1}	
Н	Ι	J	K				
$12.4^{\pm0.1}$	$0.4^{\pm 0.05}$	$4.1^{\pm 0.1}$	$5.1^{\pm 0.1}$				

Reel structure and Dimensions



Dimensio	ns List	(Unit : mm)		
а	b	с	d	
330	$22.5^{\pm 1.5}$	$100^{\pm 1.0}$	$13^{\pm 0.5}$	
e	f	g		
23 ^{±1.0}	$2.0^{\pm 0.5}$	$2.0^{\pm 0.5}$		

Direction of product insertion



[Packing : 2 000pcs/reel]

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- --- Personal computers
- --- Office automation equipment
- --- Telecommunication equipment [terminal]
- --- Test and measurement equipment
- --- Industrial control
- --- Audio visual equipment
- --- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- --- Space applications
- --- Telecommunication equipment [trunk lines]
- --- Nuclear power control equipment
- --- Medical and other life support equipment (e.g., scuba).

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